QS5U13

2.5V Drive Nch+SBD MOSFET

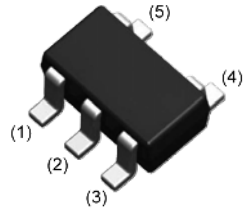
Datasheet

V_{DSS}	30V
$R_{DS(on)}$(Max.)	100mΩ
I_D	±2.0A
P_D	1.25W

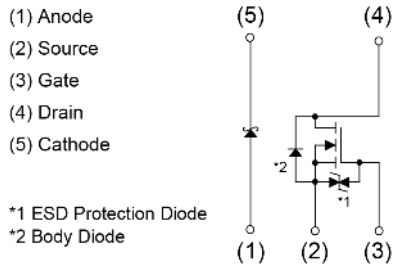
●Outline

SOT-25T

TSMT5



●Inner circuit



●Features

1) The QS5U13 combines Nch MOSFET with a Schottky barrier diode in a single TSMT5 package.
2) Low on-state resistance with fast swicthing
3) Low voltage drive (2.5V drive).
4) Built-in Low V_F schottky barrier diode.
5) Pb-free lead plating ; RoHS compliant.

●Application

Load switch, DC/ DC conversion

●Packaging specifications

Type	Packing	Embossed Tape
	Reel size (mm)	180
	Tape width (mm)	8
	Quantity (pcs)	3000
	Taping code	TR
	Marking	U13

●Absolute maximum ratings (T_a = 25°C ,unless otherwise specified)

<MOSFET>

Parameter	Symbol	Value	Unit
Drain - Source voltage	V_{DSS}	30	V
Gate - Source voltage	V_{GSS}	12	V
Continuous drain current	I_D	±2.0	A
Pulsed drain current	I_{DP}*1	±8.0	A
Continuous source current (body diode)	I_S	0.8	A
Pulsed source current (body diode)	I_{SP}*1	3.2	A
Power dissipation	P_D*3	0.9	W/element
Junction temperature	T_j	150	℃

●Absolute maximum ratings (T_a = 25°C)

<Di>

Parameter	Symbol	Value	Unit
Repetitive peak reverse voltage	V_{RM}	30	V
Reverse voltage	V_R	20	V
Forward current	I_F	0.5	A
Forward current surge peak	I_{FSM}*2	2.0	A
Power dissipation	P_D*3	0.7	W/element
Junction temperature	T_j	150	℃

<MOSFET + Di>

Parameter	Symbol	Value	Unit
Power dissipation	P_D*3	1.25	W/total
Operating junction and storage temperature range	T_{stg}	-55 to +150	℃

●Electrical characteristics (T_a = 25°C)

<MOSFET>

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Gate - Source leakage current	I_{GSS}	V_{GS} = 12V, V_{DS} = 0V	-	-	10	μA
Drain - Source breakdown voltage	$V_{(BR)DSS}$	V_{GS} = 0V, I_D = 1mA	30	-	-	V
Zero gate voltage drain current	I_{DSS}	V_{DS} = 30V, V_{GS} = 0V	-	-	1	μA
Gate threshold voltage	$V_{GS(th)}$	V_{DS} = 10V, I_D = 1mA	0.5	-	1.5	V
Static drain - source on - state resistance	$R_{DS(on)}$*4	V_{GS} = 4.5V, I_D = 2.0A	-	71	100	mΩ
		V_{GS} = 4.0V, I_D = 2.0A	-	76	107	
		V_{GS} = 2.5V, I_D = 2.0A	-	110	154	
Forward Transfer Admittance	$\|Y_{fs}\|$*4	V_{DS} = 10V, I_D = 2.0A	1.5	-	-	S

●Electrical characteristics (T_a = 25°C)

<MOSFET>

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Input capacitance	C_{iss}	V_{GS} = 0V	-	175	-	pF
Output capacitance	C_{oss}	V_{DS} = 10V	-	50	-	
Reverse transfer capacitance	C_{rss}	f = 1MHz	-	25	-	
Turn - on delay time	$t_{d(on)}$ *4	V_{DD} ≃ 15V, V_{GS} = 4.5V	-	8	-	ns
Rise time	t_r *4	I_D = 1.0A	-	10	-	
Turn - off delay time	$t_{d(off)}$ *4	R_L = 15Ω	-	21	-	
Fall time	t_f *4	R_G = 10Ω	-	8	-	

●Gate charge characteristics (T_a = 25°C)

<MOSFET>

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Total gate charge	Q_g *4	V_{DD} ≃ 15V, I_D = 2.0A V_{GS} = 4.5V	-	2.8	3.9	nC
Gate - Source charge	Q_{gs} *4		-	0.6	-	
Gate - Drain charge	Q_{gd} *4		-	0.8	-	

●Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

<MOSFET>

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Forward voltage	V_{SD} *4	V_{GS} = 0V, I_S = 3.2A	-	-	1.2	V

● **Electrical characteristics** (T_a = 25°C)

<Di>

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Forward voltage	V_F	I_F = 0.1A	-	-	0.36	V
		I_F = 0.5A	-	-	0.47	V
Reverse current	I_R	V_R = 20V	-	-	100	μA

*1 Pw ≤ 10μs, Duty cycle ≤ 1%

*2 60Hz・1 cycle

*3 Mounted on a ceramic board

*4 Pulsed

●Electrical characteristic curves <MOSFET>

Fig.1 Typical Capacitance vs. Drain - Source Voltage

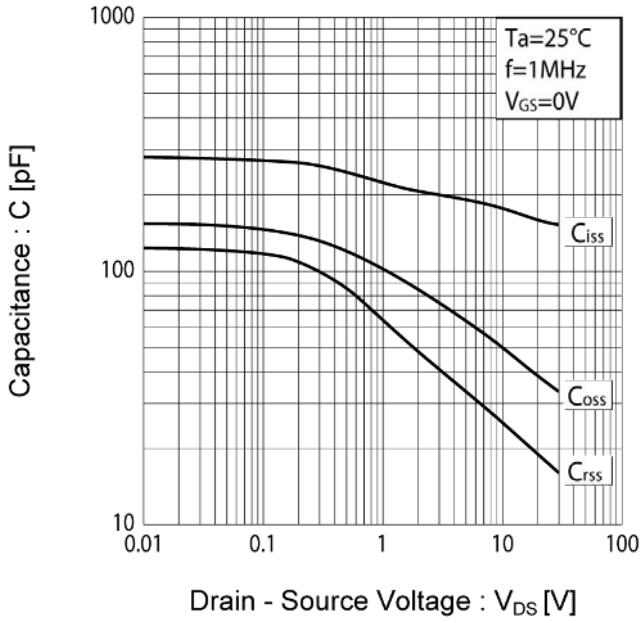


Fig.2 Switching Characteristics

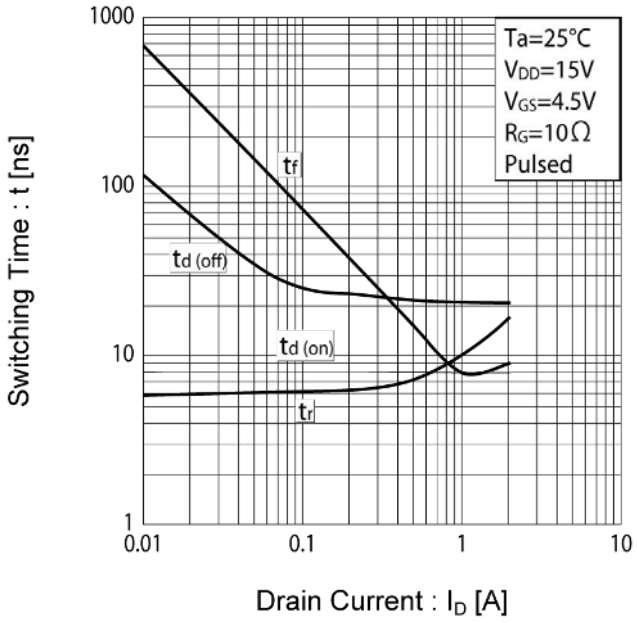


Fig.3 Dynamic Input Characteristics

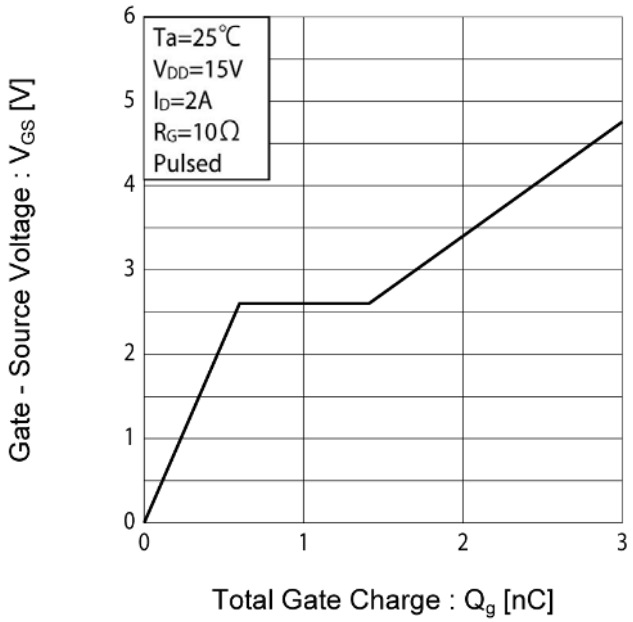
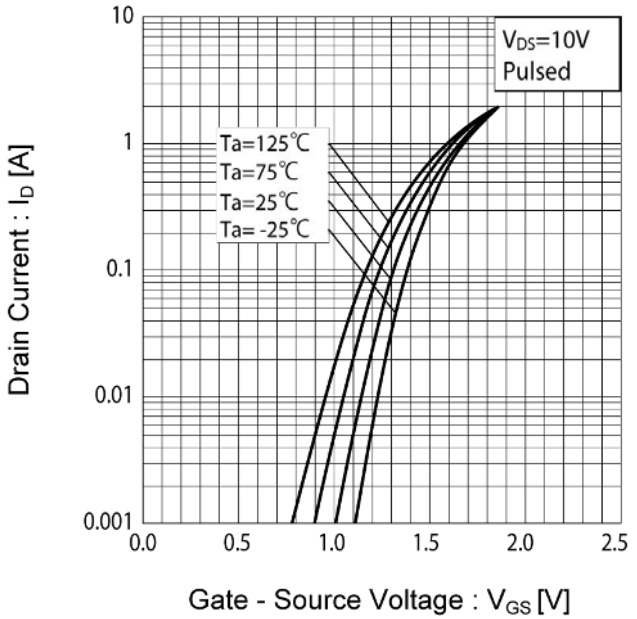


Fig.4 Typical Transfer Characteristics



●Electrical characteristic curves <MOSFET>

Fig.5 Static Drain - Source On - State Resistance vs. Gate Source Voltage

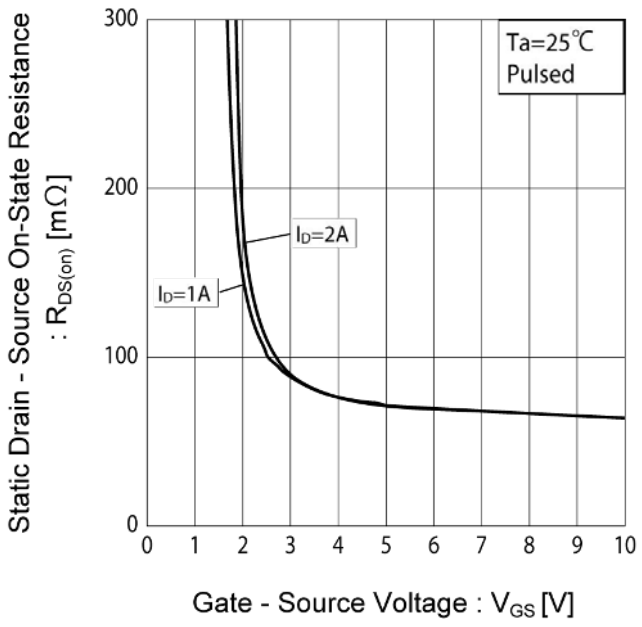


Fig.6 Source Current vs. Source Drain Voltage

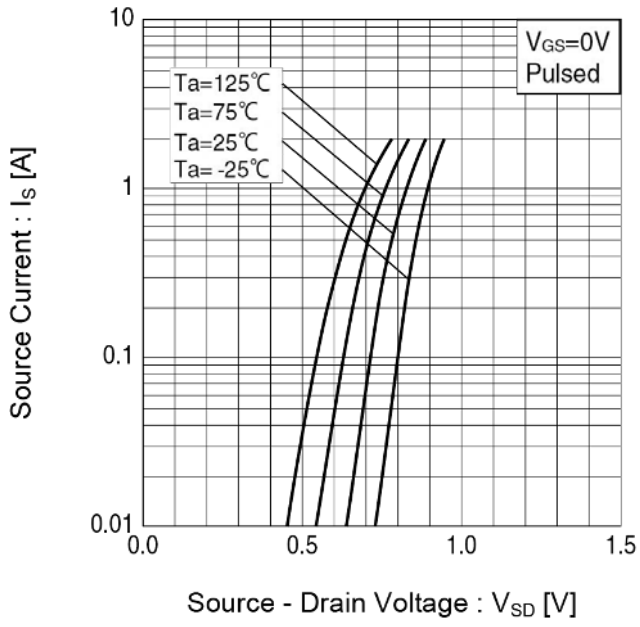


Fig.7 Static Drain - Source On - State Resistance vs. Drain Current (I)

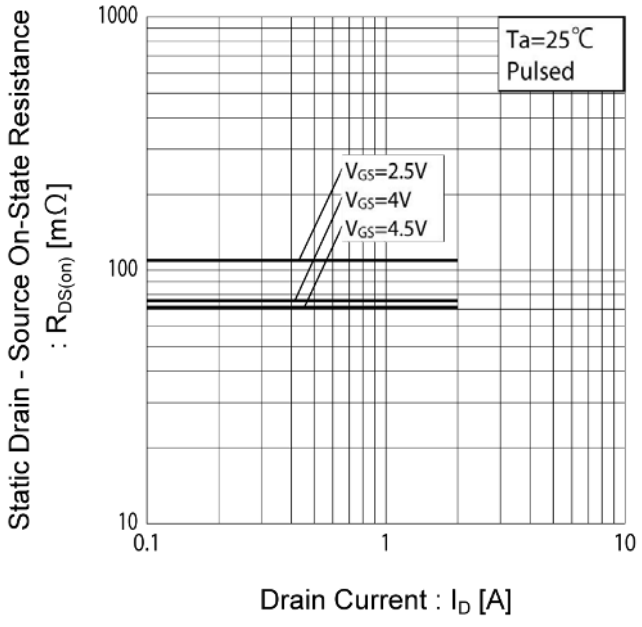
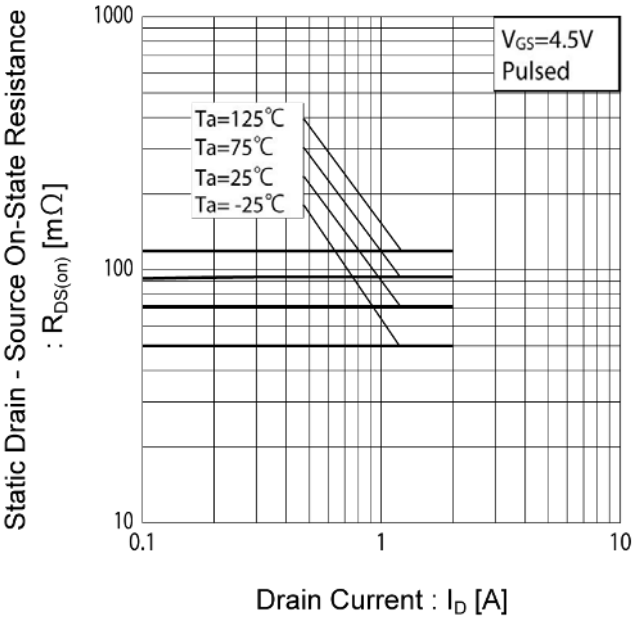


Fig.8 Static Drain - Source On - State Resistance vs. Drain Current (II)



●Electrical characteristic curves <MOSFET>

Fig.9 Static Drain - Source On - State Resistance vs. Drain Current (III)

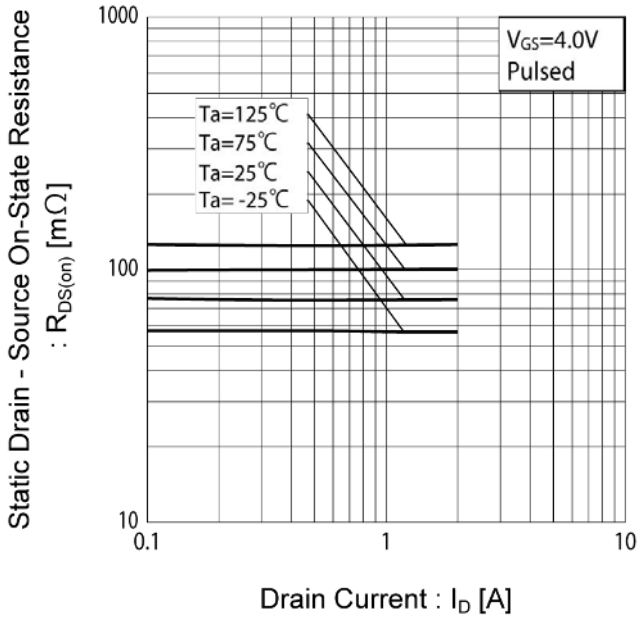
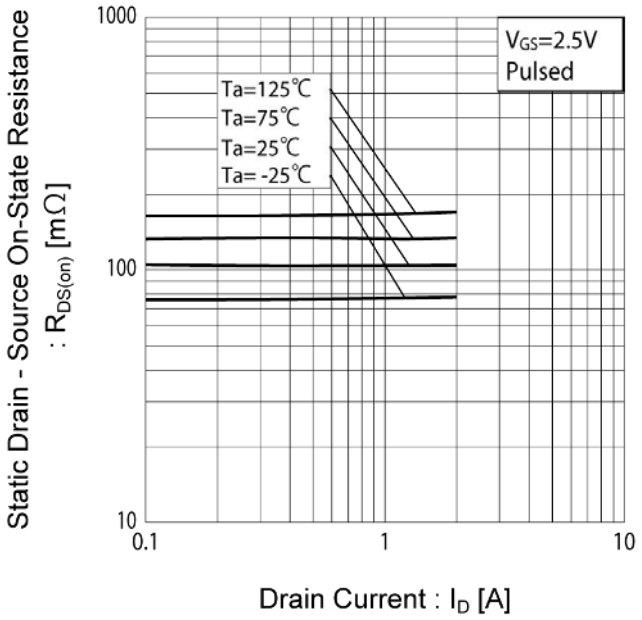


Fig.10 Static Drain - Source On - State Resistance vs. Drain Current (IV)



●Electrical characteristic curves < Diode >

Fig.11 Forward Current vs. Forward Voltage

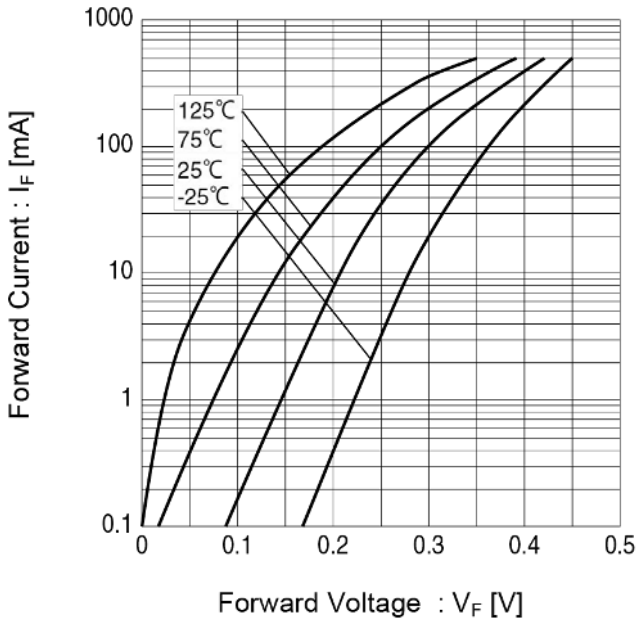
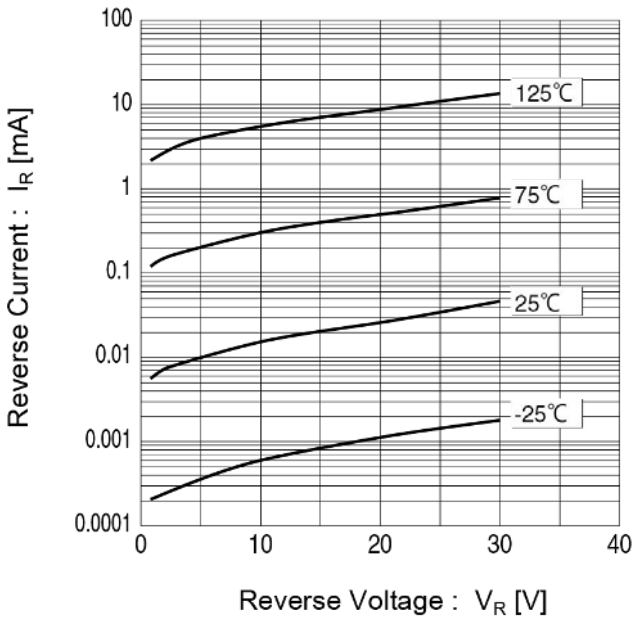


Fig.12 Reverse Current vs. Reverse Voltage



●Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

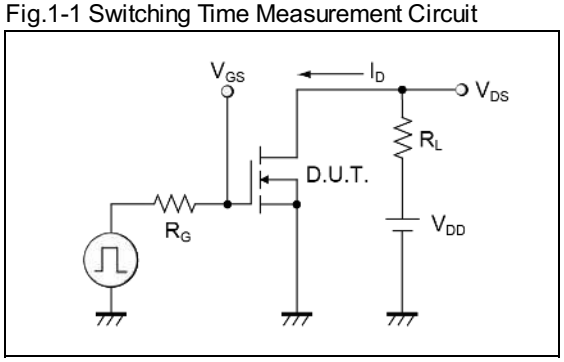


Fig.1-2 Switching Waveforms

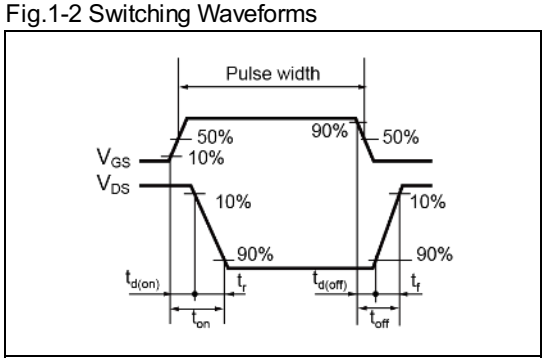


Fig.2-1 Gate Charge Measurement Circuit

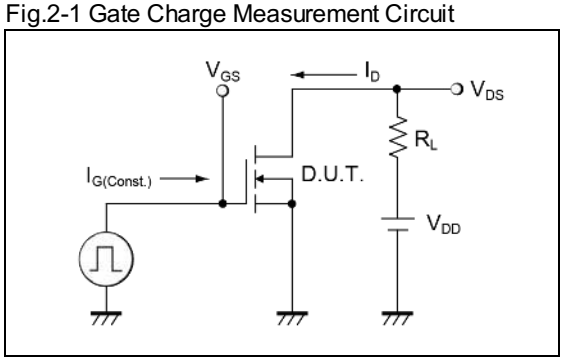
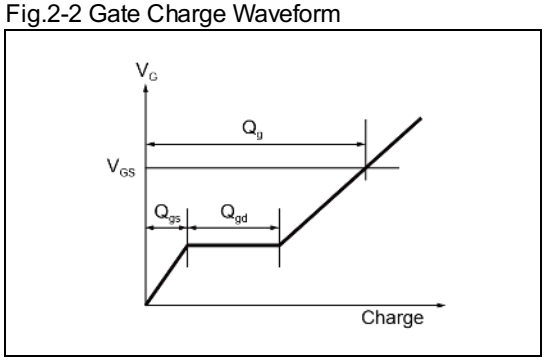


Fig.2-2 Gate Charge Waveform



●Notice

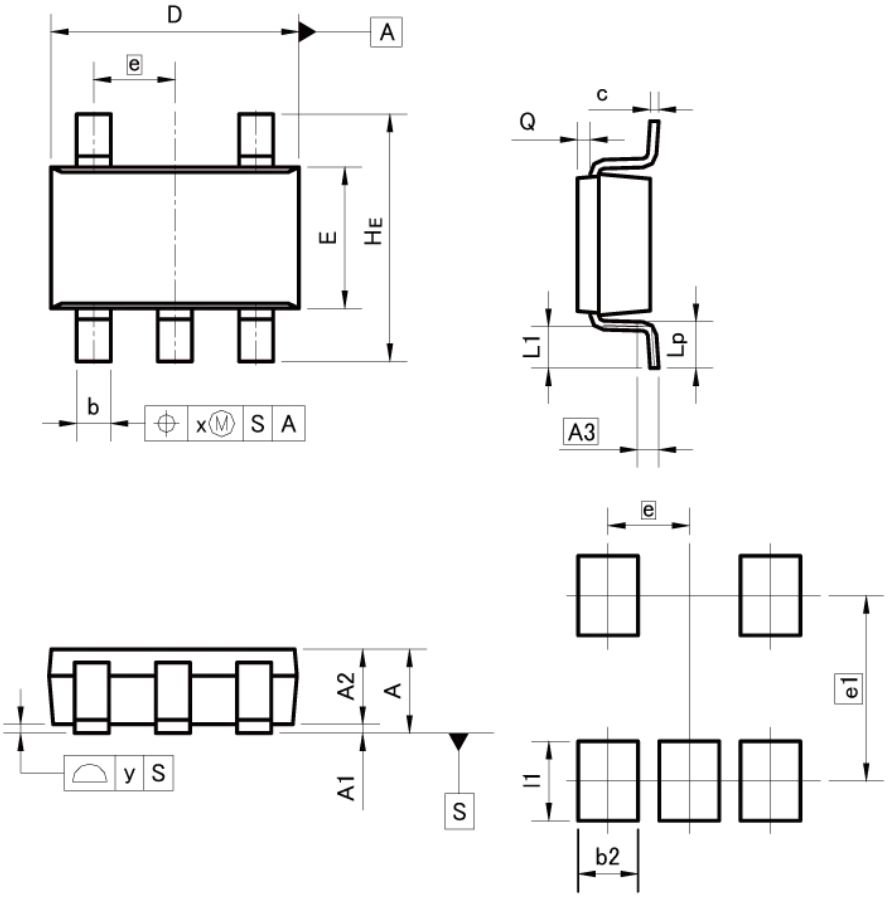
1. SBD has a large reverse leak current compared to other type of diode. Therefore, it would raise a junction temperature, and increase a reverse power loss. Further rise of inside temperature would cause a thermal runaway. This built-in SBD has low V_F characteristics and therefore, higher leak current. Please consider enough the surrounding temperature, generating heat of MOSFET and the reverse current.

2. This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

●Dimensions

TSMT5

< SOT-25T >



Pattern of terminal position areas
[Not a pattern of soldering pads]

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	–	1.00	–	0.039
A1	0.00	0.10	0.000	0.004
A2	0.75	0.95	0.030	0.037
A3	0.25		0.010	
b	0.35	0.50	0.014	0.020
c	0.10	0.26	0.004	0.010
D	2.80	3.00	0.110	0.118
E	1.50	1.80	0.059	0.071
e	0.95		0.037	
HE	2.60	3.00	0.102	0.118
L1	0.30	0.60	0.012	0.024
Lp	0.40	0.70	0.016	0.028
Q	0.05	0.25	0.002	0.010
x	–	0.20	–	0.008
y	–	0.10	–	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2		0.70	–	0.028
e1	2.10		0.083	
l1	–	0.90	–	0.035

Dimension in mm/inches

Notice

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1. Our Products are designed and manufactured for application in ordinary electronic equipment (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (Note 1), transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

JAPAN	USA	EU	CHINA
CLASSⅢ	CLASSⅢ	CLASSⅡb	CLASSⅢ
CLASSⅣ		CLASSⅢ	

2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
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   [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure

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   [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
   [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
   [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl_2, H_2S, NH_3, SO_2, and NO_2
   [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
   [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
   [f] Sealing or coating our Products with resin or other coating materials
   [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.) ; or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
   [h] Use of the Products in places subject to dew condensation

4. The Products are not subject to radiation-proof design.

5. Please verify and confirm characteristics of the final or mounted products in using the Products.

6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.

7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.

8. Confirm that operation temperature is within the specified range described in the product specification.

9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.

2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

Precautions Regarding Application Examples and External Circuits

1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.

2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of Ionizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
   [a] the Products are exposed to sea winds or corrosive gases, including Cl_2, H_2S, NH_3, SO_2, and NO_2
   [b] the temperature or humidity exceeds those recommended by ROHM
   [c] the Products are exposed to direct sunshine or condensation
   [d] the Products are exposed to high Electrostatic

2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.

3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.

4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

Precaution for Disposition

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